

2SC1890A

Silicon NPN Epitaxial

REJ03G0692-0200
(Previous ADE-208-1057)
Rev.2.00
Aug.10.2005

Application

- Low frequency high voltage amplifier
- Complementary pair with 2SA893A

Outline

RENESAS Package code: PRSS0003DA-A
(Package name: TO-92 (1))



- 1. Emitter
- 2. Collector
- 3. Base

Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	120	V
Collector to emitter voltage	V_{CEO}	120	V
Emitter to base voltage	V_{EBO}	5	V
Collector current	I_C	50	mA
Collector power dissipation	P_C	300	mW
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-55 to +150	°C

Electrical Characteristics

(Ta = 25°C)

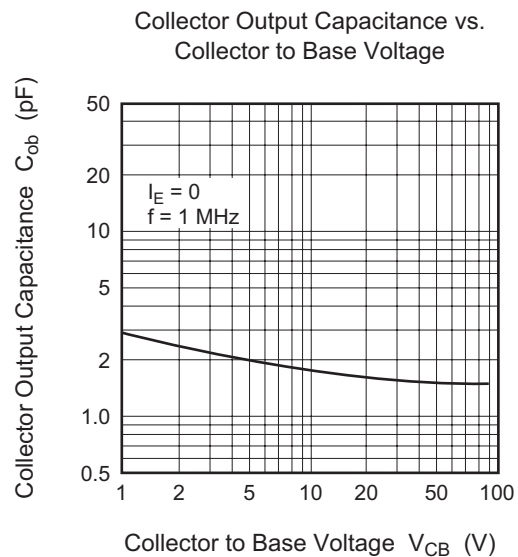
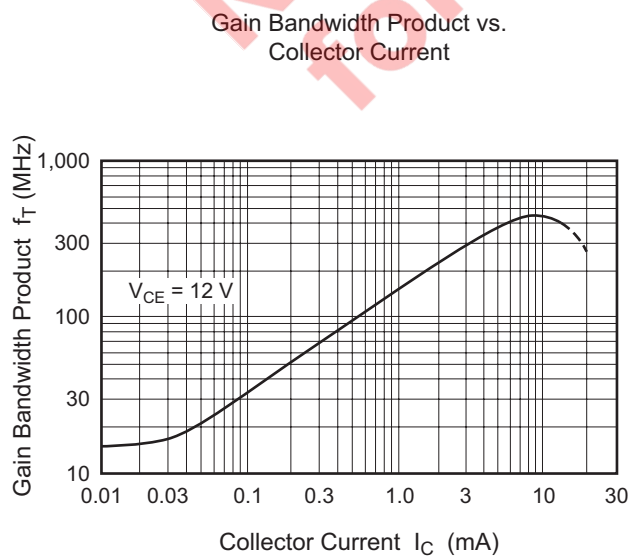
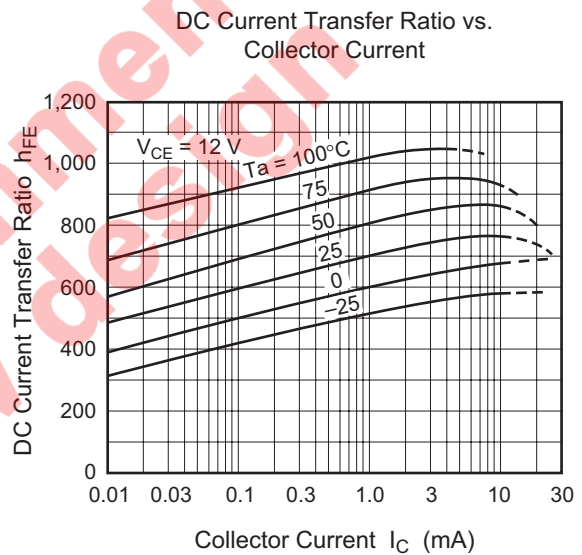
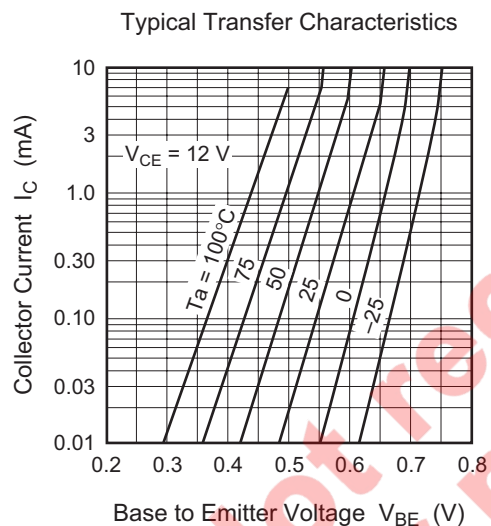
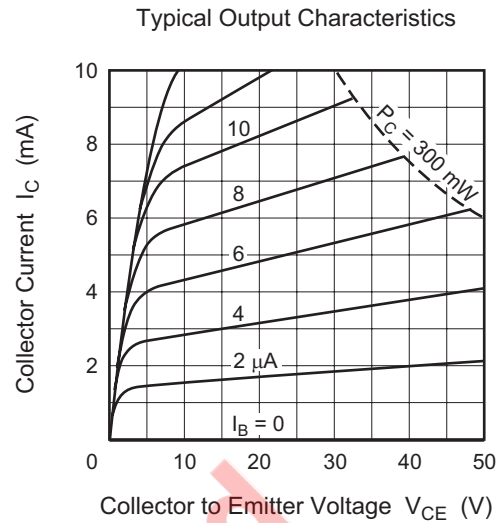
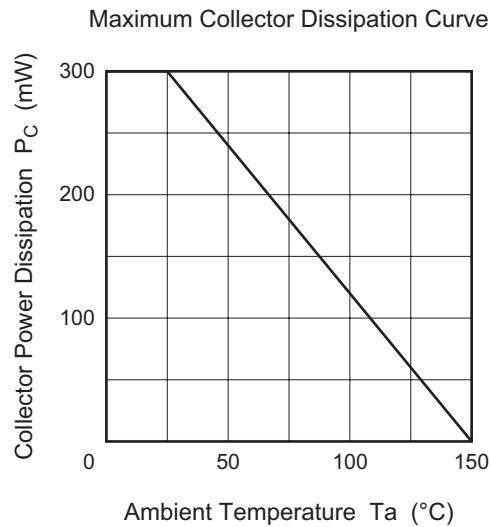
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	120	—	—	V	$I_C = 1 \text{ mA}$, $R_{BE} = \infty$
Collector cutoff current	I_{CBO}	—	—	—	μA	$V_{CB} = 75 \text{ V}$, $I_E = 0$
		—	—	0.5	μA	$V_{CB} = 100 \text{ V}$, $I_E = 0$
DC current transfer ratio	h_{FE}^{*1}	250	—	1200		$V_{CE} = 12 \text{ V}$, $I_C = 2 \text{ mA}$
Base to emitter voltage	V_{BE}	—	—	0.75	V	$V_{CE} = 12 \text{ V}$, $I_C = 2 \text{ mA}$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	—	0.5	V	$I_C = 10 \text{ mA}$, $I_B = 1 \text{ mA}$
Gain bandwidth product	f_T	—	200	—	MHz	$V_{CE} = 12 \text{ V}$, $I_C = 2 \text{ mA}$
Collector output capacitance	C_{ob}	—	1.6	—	pF	$V_{CB} = 25 \text{ V}$, $I_E = 0$, $f = 1 \text{ MHz}$
Noise figure	NF	—	2	10	dB	$V_{CE} = 6 \text{ V}$, $I_C = 50 \mu\text{A}$, $R_g = 50 \text{ k}\Omega$, $f = 1 \text{ kHz}$

Note: 1. The 2SC1890A is grouped by h_{FE} as follows.

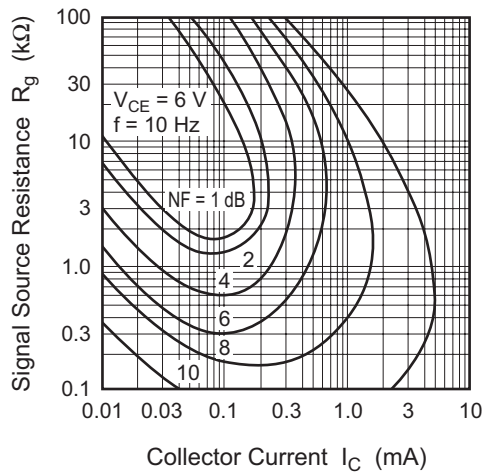
D	E	F
250 to 500	400 to 800	600 to 1200

Not recommend
for new design

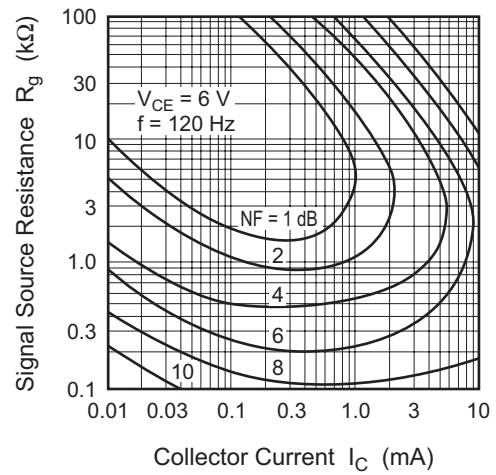
Main Characteristics



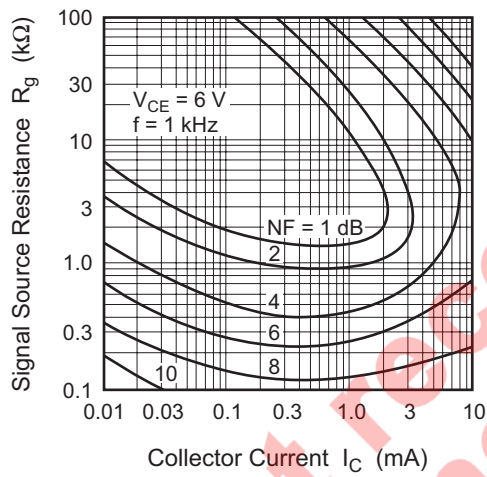
Contours of Constant Noise Figure



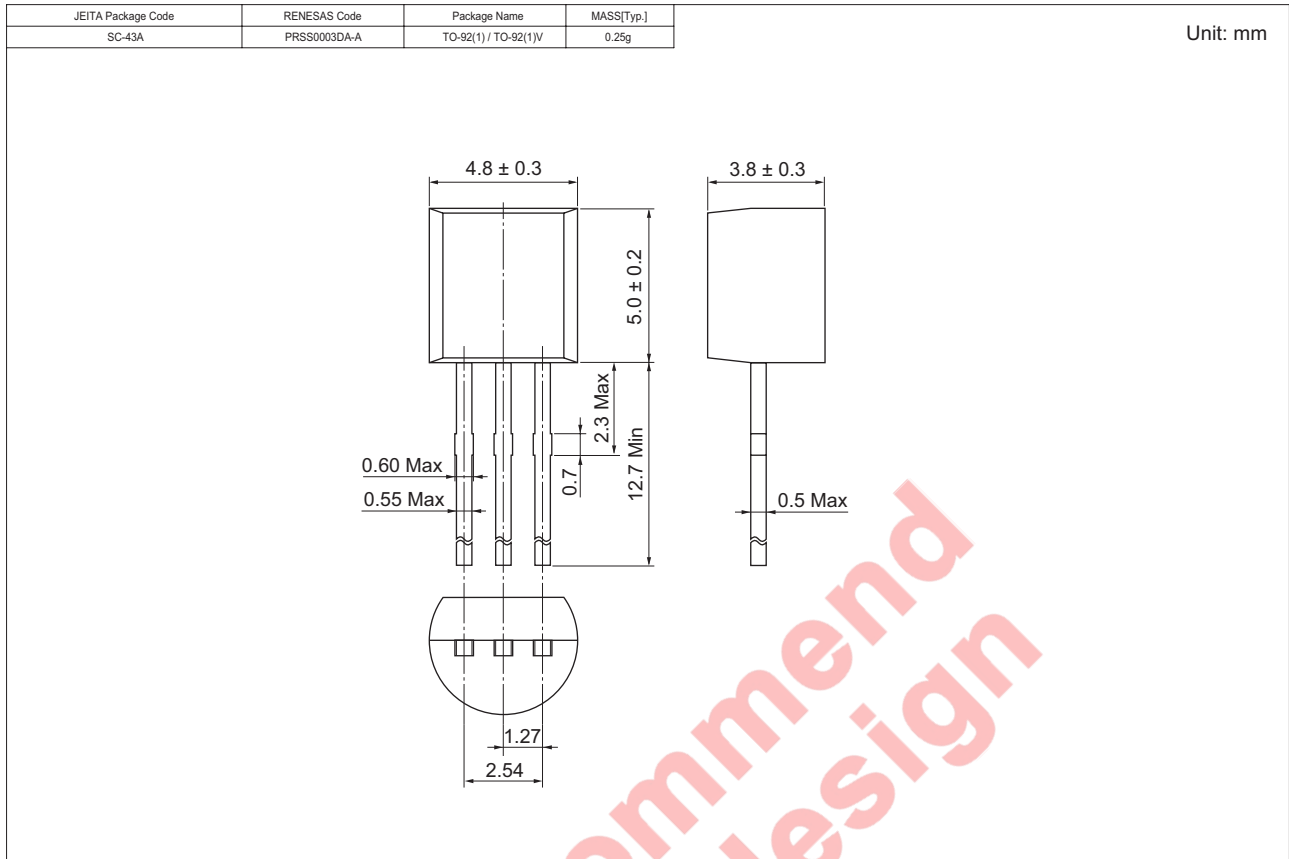
Contours of Constant Noise Figure



Contours of Constant Noise Figure



Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SC1890ADTZ	2500	Hold Box, Radial Taping
2SC1890AETZ		
2SC1890AFTZ		

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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Renesas Technology Taiwan Co., Ltd.

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Renesas Technology Singapore Pte. Ltd.

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Tel: <82> 2-796-3115, Fax: <82> 2-796-2145

Renesas Technology Malaysia Sdn. Bhd.

Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tel: <603> 7955-9390, Fax: <603> 7955-9510